

PATENT ABSTRACTS OF JAPAN

(11) Publication number : 62-242362
(43) Date of publication of application : 22. 10. 1987

(51) Int. Cl. H01L 27/15
G02B 6/12
H01L 31/02
H01S 3/18

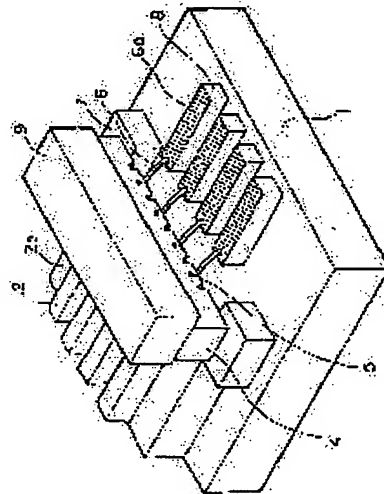
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(54) HYBRID OPTICAL WAVEGUIDE CIRCUIT

(57) Abstract:

PURPOSE: To enable installation of semiconductor laser array elements in the P-side down condition having extremely high positioning accuracy by a method wherein both of optical waveguide circuit parts and element retaining parts are projectedly provided on a substrate making the optical waveguide circuit parts so as to become higher than the element retaining part.

CONSTITUTION: A semiconductor laser array 4 is loaded on element retainers 7 in the P-side down condition as to make the edge surface on the active layer side (the P-side) of the laser array 4 to come in contact with the upper surface of the element retainers 7. Because multistage step difference are formed to the optical circuit substrate and the element retainers 7 are formed in a projecting type, when the semiconductor laser and the optical waveguide circuit are hybridizedly integrated, equipment of the element thereof can be attained in the P-side down condition having high precision, of positioning and at the same time, in the elements formed in an array, because electric connection is performed according to gold wires 6 utilizing space on the lower side of the semiconductor laser 4 without forming an electric wiring pattern on the substrate, electric wiring can be attained while maintaining electric insulation between the respective elements.



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[Date of request for examination]
[Date of sending the examiner's
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[Kind of final disposal of application
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registration]
[Date of final disposal for
application]
[Patent number]
[Date of registration]
[Number of appeal against examiner's
decision of rejection]
[Date of requesting appeal against
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